# **MMSD103T1**

Preferred Device

# **High Voltage Switching Diode**

#### **Features**

• Pb-Free Package is Available

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	250	Vdc
Peak Forward Current	ΙF	200	mAdc
Peak Forward Surge Current	I <sub>FM(surge)</sub>	625	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Forward Power Dissipation, FR–5 Board (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>F</sub>	400 3.2	mW mW/°C
Thermal Resistance, Junction-to-Case	$R_{\theta JL}$	174	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	492	°C/W
Junction and Storage Temperature Range	T <sub>J,</sub> T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



# ON Semiconductor®

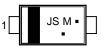
#### http://onsemi.com





SOD-123 CASE 425 STYLE 1

#### **MARKING DIAGRAM**



JS = Device Code M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMSD103T1	SOD-123	3000 / Tape & Reel
MMSD103T1G	SOD-123 (Pb-Free)	3000 / Tape & Reel

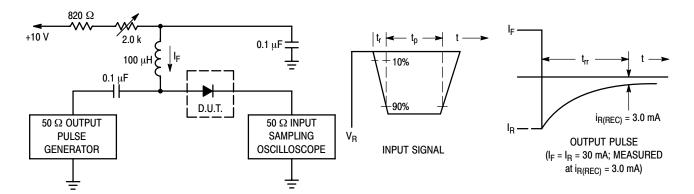
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

#### **MMSD103T1**

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current $(V_R = 200 \text{ Vdc})$ $(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I <sub>R</sub>	- -	1.0 100	μAdc
Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μAdc)	V <sub>(BR)</sub>	250	_	Vdc
Forward Voltage $(I_F = 100 \text{ mAdc})$ $(I_F = 200 \text{ mAdc})$	V <sub>F</sub>	- -	1000 1250	mV
Diode Capacitance $(V_R = 0, f = 1.0 \text{ MHz})$	C <sub>D</sub>	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30 \text{ mAdc}, R_L = 100 \Omega$ )	t <sub>rr</sub>	-	50	ns



Notes: 1. A 2.0  $k\Omega$  variable resistor adjusted for a Forward Current (IF) of 30 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.
- 3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

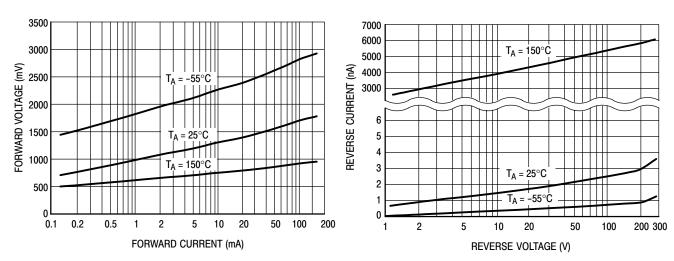


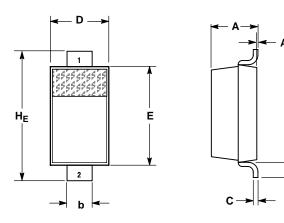
Figure 2. Forward Voltage

Figure 3. Reverse Leakage

#### MMSD103T1

#### PACKAGE DIMENSIONS

SOD-123 CASE 425-04 ISSUE E



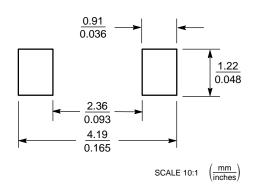
#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
C			0.15			0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
HE	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25			0.010		

STYLE 1: PIN 1. CATHODE 2. ANODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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